NSN 5961-01-201-9575

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-201-9575 **Inclosure Material:** Metal **Overall Length:** 0.915 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.687 inches Thread Size: 0.250 inches **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 45.0 reverse voltage, instantaneous all semiconductor device diode and 45.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes source cutoff current preset all semiconductor device diode and 620.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: